



MMBTA42

NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

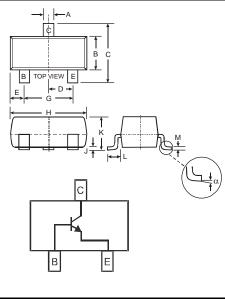
Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMBTA92)
- Ideal for Low Power Amplification and Switching
- Lead, Halogen and Antimony Free, RoHS Compliant "Green" Device (Notes 4 and 5)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking (See Page 2): K3M
- Ordering & Date Code Information: See Page 2
- Weight: 0.008 grams (approximate)

Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified



SOT-23										
Dim	Min	Max								
Α	0.37	0.51								
В	1.20	1.40								
C	2.30	2.50								
D	0.89	1.03								
Е	0.45	0.60								
G	1.78	2.05								
Н	2.80	3.00								
J	0.013	0.10								
к	0.903	1.10								
L	0.45	0.61								
м	0.085	0.180								
α	0°	8°								
All Dir	nensions	All Dimensions in mm								

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	300	V
Collector-Emitter Voltage	V _{CEO}	300	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current (Note 1) (Note 3)	IC	500	mA
Power Dissipation (Note 1)	Pd	300	mW
Thermal Resistance, Junction to Ambient (Note 1)	R _{0JA}	417	°C/W
Operating and Storage and Temperature Range	T _i , T _{STG}	-55 to +150	°C

Electrical Characteristics $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 2)					
Collector-Base Breakdown Voltage	V _{(BR)CBO}	300	—	V	$I_{C} = 100 \mu A, I_{E} = 0$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	300		V	I _C = 1.0mA, I _B = 0
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	6.0	_	V	I _E = 100μA, I _C = 0
Collector Cutoff Current	I _{CBO}	_	100	nA	$V_{CB} = 200V, I_E = 0$
Collector Cutoff Current	I _{EBO}		100	nA	$V_{CE} = 6.0V, I_{C} = 0$
ON CHARACTERISTICS (Note 2)					
		25			$I_{C} = 1.0 \text{mA}, V_{CE} = 10 \text{V}$
DC Current Gain	h _{FE}	40 40	—		$I_{C} = 10 \text{mA}, V_{CE} = 10 \text{V}$
					$I_{C} = 30 \text{mA}, V_{CE} = 10 \text{V}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		0.5	V	I _C = 20mA, I _B = 2.0mA
Base- Emitter Saturation Voltage	V _{BE(SAT)}	_	0.9	V	I _C = 20mA, I _B = 2.0mA
SMALL SIGNAL CHARACTERISTICS	· · ·				
Output Capacitance	C _{cb}		3.0	pF	$V_{CB} = 20V, f = 1.0MHz, I_E = 0$
Current Gain-Bandwidth Product	f _T	50	_	MHz	$V_{CE} = 20V, I_C = 10mA,$ f = 100MHz

Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

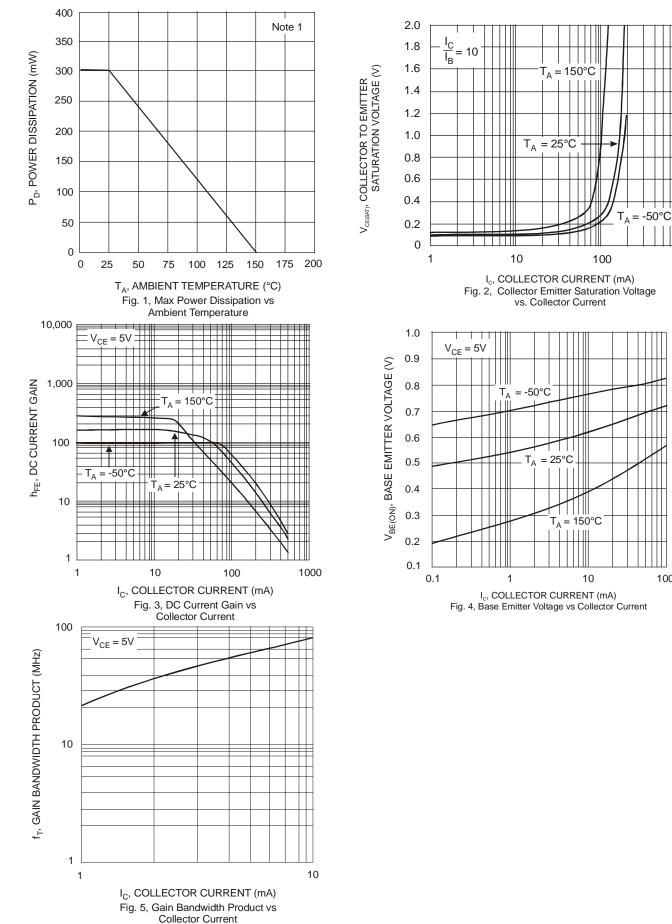
2. Short duration pulse test used to minimize self-heating effect.

When operated under collector-emitter saturation conditions within the safe operating area defined by the thermal resistance rating (R_{θJA}), power dissipation rating (P_d) and power derating curve (figure 1).

4. No purposefully added lead. Halogen and Antimony Free.

 Product manufactured with Data Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V9 are built with Non-Green Molding Compound and may contain Halogens or Sb₂O₃ Fire Retardants.





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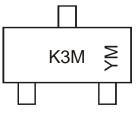


Ordering Information (Note 6)

Γ	Device	Packaging	Shipping
	MMBTA 42-7-F	SOT-23	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



K3M = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	K	L	М	Ν	Р	R	S	Т	U	V	W	Х	Y	Z
Month Code			Jan	Feb	Mar	Apr	Мау	Jun	Ju	Αι	ug 🤤	Sep	Oct	Nov	Dec
			1	2	3	4	5	6	7	8	3	9	0	Ν	D

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